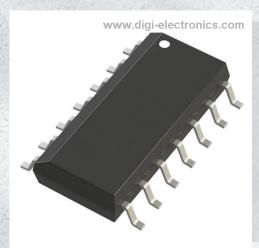


# 74HCT03D,653 Datasheet



DiGi Electronics Part Number Manufacturer Manufacturer Product Number Description Detailed Description 74HCT03D,653-DG Nexperia USA Inc. 74HCT03D,653 IC GATE NAND 4CH 2-INP 14SO NAND Gate IC 4 Channel Open Drain 14-SO

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# Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
74HCT03D,653	Nexperia USA Inc.
Series:	Product Status:
74HCT	Active
Logic Type:	Number of Circuits:
NAND Gate	4
Number of Inputs:	Features:
2	Open Drain
Voltage - Supply:	Current - Quiescent (Max):
4.5V ~ 5.5V	2 μΑ
Current - Output High, Low:	Input Logic Level - Low:
-, 4mA	0.8V
Input Logic Level - High:	Max Propagation Delay @ V, Max CL:
2V	24ns @ 4.5V, 50pF
Operating Temperature:	Mounting Type:
-40°C ~ 125°C	Surface Mount
Supplier Device Package:	Package / Case:
14-50	14-SOIC (0.154", 3.90mm Width)
Base Product Number:	
74HCT03	

# **Environmental & Export classification**

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8542.39.0001	



Product data sheet

## 1. General description

The 74HC03; 74HCT03 is a quad 2-input NAND gate with open-drain outputs. Inputs include clamp diodes that enable the use of current limiting resistors to interface inputs to voltages in excess of  $V_{CC}$ .

## 2. Features and benefits

- Wide supply voltage range from 2.0 V to 6.0 V
- CMOS low power dissipation
- High noise immunity
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- Input levels:
  - For 74HC03: CMOS level
  - For 74HCT03: TTL level
  - Complies with JEDEC standards:
    - JESD8C (2.7 V to 3.6 V)
    - JESD7A (2.0 V to 6.0 V)
- ESD protection:
  - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
  - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

## 3. Ordering information

#### Table 1. Ordering information

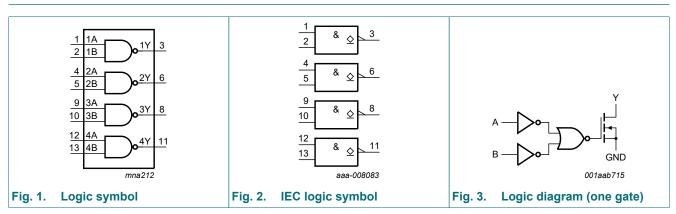
Type number	Package						
	Temperature range	Name	Description	Version			
74HC03D 74HCT03D	-40 °C to +125 °C	SO14	plastic small outline package; 14 leads; body width 3.9 mm	<u>SOT108-1</u>			
74HC03PW 74HCT03PW	-40 °C to +125 °C	TSSOP14	plastic thin shrink small outline package; 14 leads; body width 4.4 mm	<u>SOT402-1</u>			

# nexperia

# 74HC03; 74HCT03

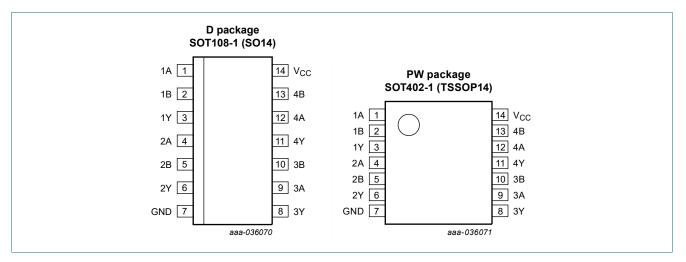
#### Quad 2-input NAND gate; open-drain output

## 4. Functional diagram



## 5. Pinning information

## 5.1. Pinning



### 5.2. Pin description

#### Table 2. Pin description

Symbol	Pin	Description
1A, 2A, 3A, 4A	1, 4, 9, 12	data input
1B, 2B, 3B, 4B	2, 5, 10, 13	data input
1Y, 2Y, 3Y, 4Y	3, 6, 8, 11	data output
GND	7	ground (0 V)
V <sub>CC</sub>	14	supply voltage

## 6. Functional description

#### Table 3. Function table

H = HIGH voltage level; L = LOW voltage level; Z = high-impedance OFF-state.

Input		Output
nA	nB	nY
L	L	Z
L	Н	Z
Н	L	Z
Н	Н	L

## 7. Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CC</sub>	supply voltage			-0.5	+7	V
Vo	output voltage		[1]	-0.5	+7	V
I <sub>IK</sub>	input clamping current	$V_{\rm I}$ < -0.5 V or $V_{\rm I}$ > $V_{\rm CC}$ + 0.5 V	[1]	-	±20	mA
I <sub>OK</sub>	output clamping current	V <sub>O</sub> < -0.5 V	[1]	-	-20	mA
I <sub>O</sub>	output current	-0.5 V < V <sub>O</sub>		-	-25	mA
I <sub>CC</sub>	supply current			-	50	mA
I <sub>GND</sub>	ground current			-50	-	mA
T <sub>stg</sub>	storage temperature			-65	+150	°C
P <sub>tot</sub>	total power dissipation		[2]	-	500	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SOT108-1 (SO14) package: Ptot derates linearly with 10.1 mW/K above 100 °C.

For SOT402-1 (TSSOP14) package: Ptot derates linearly with 7.3 mW/K above 81 °C.

## 8. Recommended operating conditions

#### Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	74HC03		74HCT03			Unit	
			Min	Тур	Max	Min	Тур	Max	
V <sub>CC</sub>	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
Vo	output voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 2.0 V	-	-	625	-	-	-	ns/V
		V <sub>CC</sub> = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V <sub>CC</sub> = 6.0 V	-	-	83	-	-	-	ns/V

## 9. Static characteristics

#### Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol Parameter		Conditions		25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Мах	Min	Max	1
74HC03										1
V <sub>IH</sub>	HIGH-level	V <sub>CC</sub> = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
	input voltage	V <sub>CC</sub> = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
		V <sub>CC</sub> = 6.0 V	4.2	3.2	-	4.2	-	4.2	-	V
V <sub>IL</sub>	LOW-level	V <sub>CC</sub> = 2.0 V	-	0.8	0.5	-	0.5	-	0.5	V
	input voltage	V <sub>CC</sub> = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	2.8	1.8	-	1.8	-	1.8	V
V <sub>OL</sub>	LOW-level	$V_{I} = V_{IH}$ or $V_{IL}$								
	output voltage	I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.0 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 6.0 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 4.5 V	-	0.15	0.26	-	0.33	-	0.4	V
		I <sub>O</sub> = 5.2 mA; V <sub>CC</sub> = 6.0 V	-	0.16	0.26	-	0.33	-	0.4	V
I <sub>I</sub>	input leakage current	$V_1 = V_{CC}$ or GND; $V_{CC} = 6.0 V$	-	0.1	-	-	±1	-	±1	μA
l <sub>oz</sub>	OFF-state output current	$V_{I} = V_{IL}; V_{CC} = 6.0 \text{ V};$ $V_{O} = V_{CC} \text{ or GND}$	-	-	±0.5	-	±5.0	-	±10	μA
l <sub>cc</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0$ V	-	2.0	-	-	20	-	40	μA
CI	input capacitance		-	3.5	-	-	-	-	-	pF
74HCT0	3						I			-
V <sub>IH</sub>	HIGH-level input voltage	$V_{CC}$ = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	2.0	-	V
V <sub>IL</sub>	LOW-level input voltage	$V_{CC}$ = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	-	0.8	V
V <sub>OL</sub>	LOW-level	$V_{I} = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 V$								
	output voltage	I <sub>O</sub> = 20 μA	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 4.0 mA	-	0.15	0.26	-	0.33	-	0.4	V
I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	±0.1	-	±1	-	±1	μA
l <sub>oz</sub>	OFF-state output current	$V_{I} = V_{IL}$ ; $V_{CC} = 5.5 V$ ; $V_{O} = V_{CC}$ or GND	-	-	±0.5	-	±5.0	-	±10	μA
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	2.0	-	20	-	40	μA
∆I <sub>CC</sub>	additional supply current	per input pin; $V_I = V_{CC} - 2.1 \text{ V}; I_O = 0 \text{ A};$ other inputs at $V_{CC}$ or GND; $V_{CC} = 4.5 \text{ V}$ to 5.5 V	-	100	360	-	450	-	490	μA
CI	input capacitance		-	3.5	-	-	-	-	-	pF

## **10.** Dynamic characteristics

#### Table 7. Dynamic characteristics

GND = 0 V;  $C_L = 50 pF$ ; for test circuit, see Fig. 5.

Symbol Parameter		Conditions		25 °C		-40 °C to +85 °C	-40 °C to +125 °C	Unit	
				Min	Тур	Max	Max	Max	
74HC03									
t <sub>pd</sub>	propagation	nA, nB to nY; see <u>Fig. 4</u>	[1]						
	delay	V <sub>CC</sub> = 2.0 V		-	28	95	120	145	ns
		V <sub>CC</sub> = 4.5 V		-	10	19	24	29	ns
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF		-	8	-	-	-	ns
		V <sub>CC</sub> = 6.0 V		-	8	16	20	25	ns
t <sub>t</sub>	transition time	see <u>Fig. 4</u>	[2]						
		V <sub>CC</sub> = 2.0 V		-	19	75	95	110	ns
		V <sub>CC</sub> = 4.5 V		-	7	15	19	22	ns
		V <sub>CC</sub> = 6.0 V		-	6	13	16	19	ns
C <sub>PD</sub>	power dissipation capacitance	per package; V <sub>I</sub> = GND to V <sub>CC</sub>	[3]	-	4	-	-	-	pF
74HCT0	3								
t <sub>pd</sub>	propagation	nA, nB to nY; see <u>Fig. 4</u>	[1]						
	delay	V <sub>CC</sub> = 4.5 V		-	12	24	30	36	ns
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF		-	10	-	-	-	ns
t <sub>t</sub>	transition time	V <sub>CC</sub> = 4.5 V; see <u>Fig. 4</u>	[2]	-	7	15	19	22	ns
C <sub>PD</sub>	power dissipation capacitance	per package; V <sub>I</sub> = GND to V <sub>CC</sub> - 1.5 V	[3]	-	4	-	-	-	pF

[1]  $t_{pd}$  is the same as  $t_{PLZ}$  and  $t_{PZL}$ .

[1]  $t_{pd}$  is the same as  $t_{THL}$ . [2]  $t_t$  is the same as  $t_{THL}$ . [3]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu$ W):  $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$  where:

 $f_i$  = input frequency in MHz;

 $f_0$  = output frequency in MHz;

 $C_{I}$  = output load capacitance in pF;

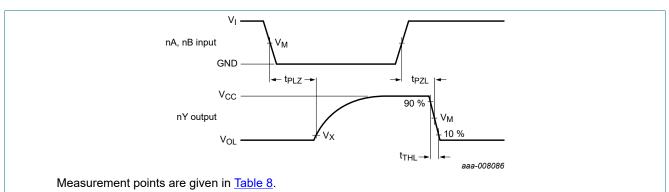
V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;  $\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

# 74HC03; 74HCT03

#### Quad 2-input NAND gate; open-drain output

## 10.1. Waveforms and test circuit

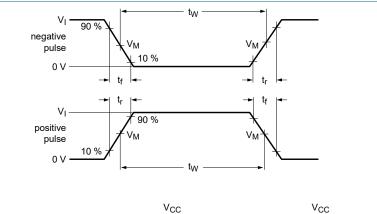


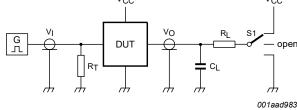
 $V_{\text{OL}}$  and  $V_{\text{OH}}$  are typical voltage output levels that occur with the output load.

#### Fig. 4. Input to output propagation delays

#### Table 8. Measurement points

Туре	Input	Output		
	V <sub>M</sub>	V <sub>M</sub>	V <sub>X</sub>	
74HC03	0.5 × V <sub>CC</sub>	0.5 × V <sub>CC</sub>	0.1 × V <sub>CC</sub>	
74HCT03	1.3 V	1.3 V	0.1 × V <sub>CC</sub>	





Test data is given in Table 9.

Definitions test circuit:

 $R_T$  = termination resistance should be equal to output impedance  $Z_o$  of the pulse generator;

 $C_L$  = load capacitance including jig and probe capacitance.

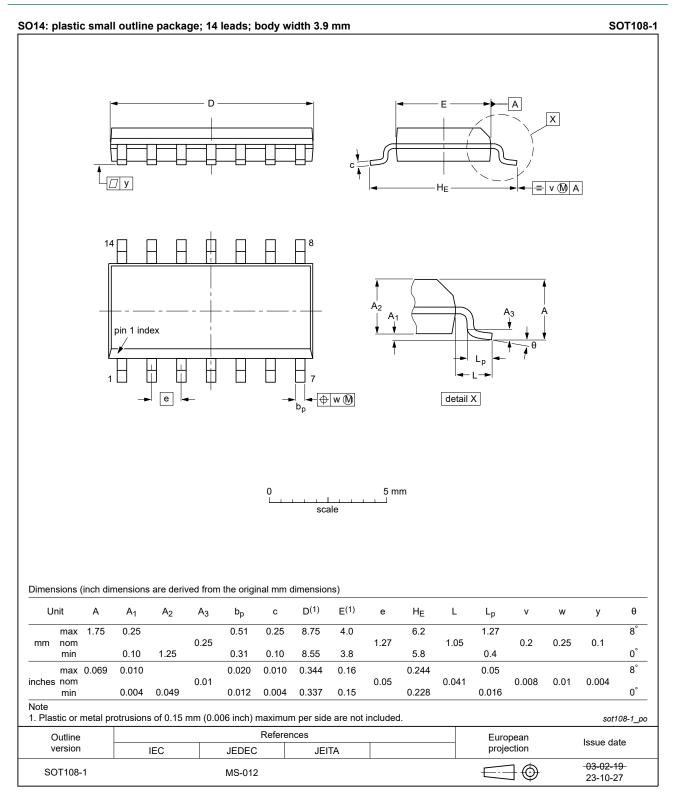
#### Fig. 5. Test circuit for measuring switching times

#### Table 9. Test data

Туре	Input		Load	S1 position	
	VI	t <sub>r</sub> , t <sub>f</sub>	CL	RL	t <sub>PZL</sub> , t <sub>PLZ</sub>
74HC03	V <sub>CC</sub>	6 ns	15 pF, 50 pF	1 kΩ	V <sub>CC</sub>
74HCT03	3.0 V	6 ns	15 pF, 50 pF	1 kΩ	V <sub>CC</sub>

74HC\_HCT03

## 11. Package outline



#### Fig. 6. Package outline SOT108-1 (SO14)

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# 74HC03; 74HCT03

#### Quad 2-input NAND gate; open-drain output

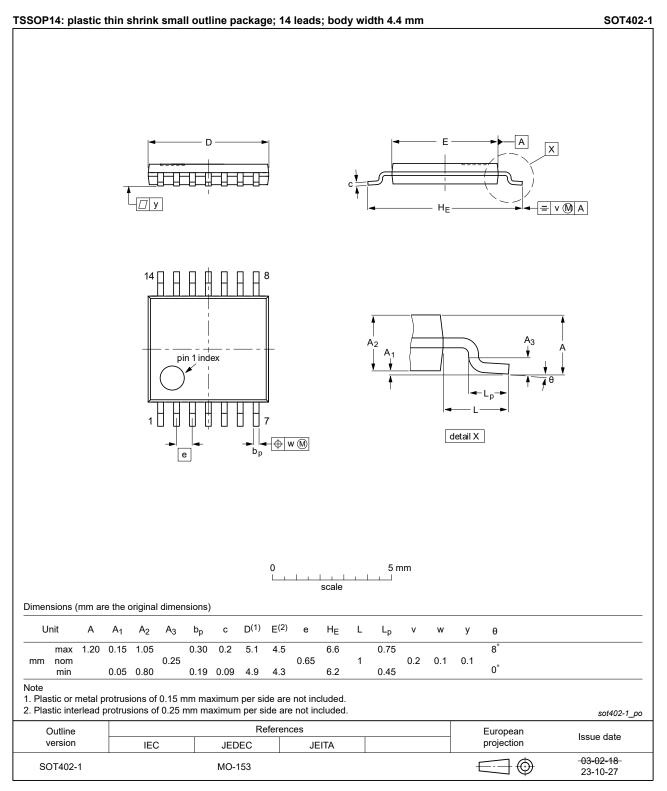


Fig. 7. Package outline SOT402-1 (TSSOP14)

# 12. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
TTL	Transistor-Transistor Logic

# 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
74HC_HCT03 v.7	20240216	Product data sheet	-	74HC_HCT03 v.6		
Modifications:		<u>ing. 0</u> , <u>ing. 7</u> . Alighed 00 and 10001 package outline drawings to JEDEO 100-012 and				
74HC_HCT03 v.6	20210810	Product data sheet	-	74HC_HCT03 v.5		
Modifications:	<ul> <li><u>Section 2</u> updated.</li> <li>Type number 74HC03DB (SOT337-1/SSOP14) removed.</li> </ul>					
74HC_HCT03 v.5	20210107	Product data sheet	-	74HC_HCT03 v.4		
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Type number 74HCT03DB (SOT337-1 / SSOP14) removed.</li> <li><u>Section 7</u>: Derating values for P<sub>tot</sub> total power dissipation have been updated.</li> </ul>					
74HC_HCT03 v.4	20151127	Product data sheet	-	74HC_HCT03 v.3		
Modifications:	Type numbers 74HC03N and 74HCT03N (SOT27-1) removed.					
74HC_HCT03 v.3	20130627	Product data sheet	-	74HC_HCT03_CNV v.2		
Modifications:	guidelines o	guidelines of NXP Semiconductors.				
74HC_HCT03_CNV v.2	19970827	Product specification	-	-		

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# 74HC03; 74HCT03

#### Quad 2-input NAND gate; open-drain output

## 14. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
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## Nexperia

# 74HC03; 74HCT03

#### Quad 2-input NAND gate; open-drain output

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74HC\_HCT03



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